

General Description

The MX7845 is a 12-bit, voltage-output, 4-quadrant, multiplying digital-to-analog converter (DAC). A precision internal output amplifier and thin-film resistors, lasertrimmed at the wafer level, maintain accuracy over the full operating temperature range. The output amplifier is internally compensated and drives $\pm 10V$ into a $2k\Omega$ load.

The MX7845 has buffered latches that are easily interfaced with microprocessors. Data is transferred into the input register from a 12-bit-wide data path. The input registers are controlled by standard CHIP SELECT (CS) and WRITE (WR) signals. For stand-alone operation, the CS and WR inputs are grounded, making all latches transparent. All logic inputs are level-triggered and compatible with TTL and +5V CMOS logic levels. For a detailed description of MX7845 operation, refer to the MAX501/MAX502 data sheet.

Applications

Automatic Test Equipment Digital Attenuators Programmable Power Supplies Programmable-Gain Amplifiers Digital to 4-20mA Converters

Features

- **♦ Complete MDAC with Output Amplifier**
- ♦ 4-Quadrant Multiplication
- ◆ Guaranteed Monotonic (T_{MIN} to T_{MAX})
- ♦ Matched Application Resistors
- ♦ Small 0.3" 24-Pin DIP Package

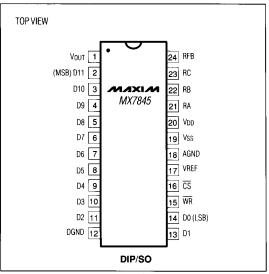
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MX7845JN	0°C to +70°C	24 Narrow Plastic DIP
MX7845KN	0°C to +70°C	24 Narrow Plastic DIP
MX7845JR	0°C to +70°C	24 Wide SO
MX7845KR	0°C to +70°C	24 Wide SO
MX7845JP	0°C to +70°C	28 PLCC
MX7845KP	0°C to +70°C	28 PLCC
MX7845J/D	0°C to +70°C	Dice*
MX7845AEWG	-40°C to +85°C	24 Wide SO
MX7845BEWG	-40°C to +85°C	24 Wide SO
MX7845AQ	-40°C to +85°C	24 Narrow CERDIP
MX7845BQ	-40°C to +85°C	24 Narrow CERDIP
MX7845SE	-55°C to +125°C	28 LCC**
MX7845SQ	-55°C to +125°C	24 Narrow CERDIP**
MX7845TQ	-55°C to +125°C	24 Narrow CERDIP**

- Contact factory for dice specifications.
- Contact factory for availability and processing to MIL-STD-883.

	Fund	ctional Diagran
VREF R R	R 2R 2R 2R D0	RA RB RC RFB 4R 2R 2R R
(MSB)	(LSB)	D AMPLIFIER CIRCUIT

Pin Configuration



/VI/IXI/VI_

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ABSOLUTE MAXIMUM RATINGS

V _{DD} to DGND	Digital Input Voltage to DGND0.3V, VDD + 0.3V
Vss to DGND	Continous Power Dissipation (any package)
VREF to AGND	to +75°C
VRFB to AGND	derate above +75°C
V _{RA} to AGND	Operating Temperature Ranges:
V _{RB} to AGND	MX7845J_/K0°C to +70°C
V _{RC} to AGND	MX7845A_/B40°C to +85°C
Vout to AGND (Note 1) VDD + 0.3V, Vss - 0.3V	MX7845S_/T55°C to +125°C
V _{DD} to AGND	Storage Temperature Range65°C to +150°C
AGND to DGND0.3V, V _{DD}	Lead Temperature (soldering, 10 sec) +300°C

Note 1: Vout may be shorted to AGND, VDD, or VSS if the package power dissipation is not exceeded.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{DD} = +15V \pm 5\%, V_{SS} = -15V \pm 5\%, V_{REF} = +10V, AGND = DGND = 0V, V_{OUT}$ connected to RFB, $R_L = 2k\Omega$, $C_L = 100pF$, $T_A = T_{MIN}$ to T_{MAX} , all grades, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ACCURACY							
Resolution	N			12			Bits
		T _A = +25°C	MX7845K/B/T			±1/2	
		1A = +25 C	MX7845J/A/S			±1]
Relative Accuracy (Note 2)	INT		MX7845K			±3/4	LSB
			MX7845J/B/T			±1]
			MX7845A			±3/2	
			MX7845S			±2	
Differential Nonlinearity	DNL					±1	LSB
Zero-Code Offset Error (Note 3)		T _A = +25°C	MX7845K/B/T			±1	mV
		1A = +25 C	MX7845J/A/S			±2	
			MX7845K/B			±3	
			MX7845J/A/T			±4	
			MX7845S			±5	
Offset Temperature Coefficient	ΔVOS/ ΔTemp				±5		μV/°C
		RFB, V _{OUT}	MX7845K/B/T			±3	
		connected	MX7845J/A/S			±6	LSB
Gain Error		RC or RB, V _{OUT} con- nected; VREF = 5V	MX7845K/B/T			±6	
,		nected; VREF = 5V	MX7845J/A/S			±9	
		RA, Vout	MX7845K/B/T			±8	
		connected; VREF = 2.5V	MX7845J/A/S			±10	
Gain Temperature Coefficient	ΔGain/ ΔTemp	RFB, V _{OUT} connected			±2		ppm o
Reference Input Resistance				8	12	16	kΩ
Application Resistor Ratio Matching		RA to RB to RC matchin	ng			0.5	%

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = +15V \pm 5\%, V_{SS} = -15V \pm 5\%, V_{REF} = +10V, AGND = DGND = 0V, V_{OUT} connected to RFB, R_L = 2k\Omega, C_L = 100pF, T_A = T_{MIN}$ to T_MAX, all grades, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
DIGITAL INPUTS	·						
Input Current	liN	V _{IN} = 0V and V _{DD}			±1	μА	
Input Low Voltage	VIL				8.0	V	
Input High Voltage	VIH	•	2.4			V	
Input Capacitance	CIN			5		pF	
POWER REQUIREMENTS						_	
Supply Voltage (Note 4)	V _{DD}		14.25		15.75	V	
Supply Voltage (Note 4)	Vss		-14.25		-15.75		
Supply Current	I _{DD}	V _{OUT} unloaded			10	mA	
	ISS	Vout unloaded			4	1112	
Power-Supply Rejection	PSR	V _{DD} only, VREF = -10V			±0.2	%/%	
	Pon	V _{SS} only			±0.2	76) 76	

Note 2: Guaranteed monotonic over temperature.

Note 3: DAC register loaded with all 0s.

Note 4: The MX7845 can operate from ±12V supplies.

TIMING CHARACTERISTICS

 $(VDD = +15V \, \&5\%, \, VSS = -15V \, \&5\%, \, VREF = +10V, \, AGND = DGND = 0V, \, T_A = T_{MIN} \, to \, T_{MAX}, \, all \, grades, \, unless \, otherwise \, noted.) \, (Note \, 5)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
-		T _A = +25°C	100				
Chip Select to Write-Setup Time	tcs	MX7845J/K/A/B	135			ns	
		MX7845S/T	140				
		$T_A = +25^{\circ}C$	0				
Chip Select to Write-Hold Time	tсн	MX7845J/K/A/B	0			ns	
		MX7845S/T	0				
		T _A = +25°C	100				
Write Pulse Width	twn	MX7845J/K/A/B	135			ns	
		MX7845S/T	140				
		T _A = +25°C	100				
Data-Setup Time	tps	MX7845J/K/A/B	100			ns	
		MX7845S/T	120				
Date Hald Time	+	T _A = +25°C	20			ns	
Data-Hold Time	t _D H		20] "	

Note 5: All input signal rise and fall times measured from 10% to 90% of +5V; $t_r = t_f = 20$ ns. Timing measurement reference is $(V_{IH} + V_{IL})/2$.

AC PERFORMANCE CHARACTERISTICS

(TA = TMIN to TMAX, all grades, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
DYNAMIC PERFORMANCE				_			
Output-Voltage Settling Time (Note 7)	ts	$V_{OUT} LOAD = 2k\Omega$, $100pF$			2.5	5.0	μs
Slew Rate	SR	Vout LOAD = 2k	Ω, 100pF		7		V/µs
DAC Glitch Impulse (Note 8)					450		(nV)(s)
Multiplying Feedthrough Error (Note 9)					5		mV _{p-p}
Unity-Gain Small-Signal Bandwidth (Note 10)		Vout, RFB conne	ected		600		kHz
Full-Power Bandwidth (Note 11)		Vout, RFB conne	ected, $R_L = 2k\Omega$		250		kHz
Total Harmonic Distortion (Note 12)	THD				-90		dB
OUTPUT CHARACTERISTICS (Note 13)							
Open-Loop Gain	Avo	$V_{OUT} = \pm 10V, R_L = 2k\Omega$		85			dB
Output Voltage Swing	Vo	$R_L = 2k\Omega$, $C_L = 1$	00pF	±10			V
Output Resistance	_ Ro	RFB, Vout conne	ected		0.2		Ω
Short-Circuit Current		VOUT, AGND con	nected; T _A = +25°C		15		mA
			0.1Hz to 10Hz		2		μVRMS
			f = 10Hz		250		
Output Noise Voltage (Note 14)		T _A = +25°C	f = 100Hz		100		
			f = 1kHz		50		nV√Hz
			f = 10kHz		50]
			f = 100kHz		50		

Note 6: AC PERFORMANCE CHARACTERISTICS are included for design guidance and are not subject to test. Note 7: Settling to 0.01% of full-scale range. DAC register alternately loaded with all 0s and all 1s. Note 8: Measured with VREF = 0V. DAC register alternately loaded with all 1s and all 0s. Note 9: VREF = $\pm 10V$, 10kHz sine wave. DAC register loaded with all 0s. Note 10: DAC register loaded with all 1s. VREF = $\pm 100V_{p-p}$ sine wave. Note 11: DAC register loaded with all 1s. VREF = $\pm 100V_{p-p}$ sine wave. Note 12: VREF = $\pm 00V_{p-p}$ sine wave. Note 13: $\pm 00V_{p-p}$ sine wave. Note 13: $\pm 00V_{p-p}$ sine wave. Note 14: Includes output amplifier noise and Johnson Noise of RFB.

Pin Description

DIP/SO	PLCC/ LCC	NAME	FUNCTION
PIN	PIN		
1	2	Vout	Voltage Output
2-11	3-7, 9-13	D11-D2	Data Bits 2 to 11 (MSB)
12	14	DGND	Digital Ground
13, 14	16, 17	D1, D0	Data Bits 0 to 1 (LSB)
15	18	WR	Write Input. Active Low.
16	19	CS	Chip-Select Input. Active Low.
17	20	VREF	Reference Input to DAC
18	21	AGND	Analog Ground

DIP/SO	PLCC/ LCC	NAME	FUNCTION
PIN	PIN		
19	23	V _{SS}	-12V to -15V Supply Voltage Input
20	24	V_{DD}	+12V to +15V Supply Voltage Input
21	25	RA	Scaling Resistor: RA = 4RFB
22	26	RB	Scaling Resistor: RB = 2RFB
23	27	RC	Scaling Resistor: RC = 2RFB
24	28	RFB	Feedback Resistor
	1, 8, 15, 22	N.C.	No Connect

For application information, refer to the MAX501/MAX502 data sheet.

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